

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L2	0	1 and ((laser near ink) or (ink near marking))	USPAT	2003/09/15 18:58
2	BRS	L1	10	((ic or (integrat\$3 near circuit) or semiconductor) with package\$1) with (cleaning)) and (plasma with chamber)	USPAT	2003/09/15 19:07
3	BRS	L3	167	(plasma with chamber) and (((ic or (integrat\$3 near circuit) or semiconductor) with package\$1))	USPAT	2003/09/15 19:18
4	BRS	L4	60	3 and cleaning	USPAT	2003/09/15 19:09
5	BRS	L5	1	4 and (ink with mark\$3)	USPAT	2003/09/15 19:09
6	BRS	L6	0	3 and (laser with ink with marking)	USPAT	2003/09/15 19:15
7	BRS	L7	1	(laser with ink with marking) and (plasma with chamber)	USPAT	2003/09/15 19:15
8	BRS	L8	0	(plasma with chamber) and (((ic or (integrat\$3 near circuit) or semiconductor))) and ((ink with	USPAT	2003/09/15 19:19
9	BRS	L9	8	(plasma with chamber) and (((ic or (integrat\$3 near circuit) or semiconductor))) and ((ink with	USPAT	2003/09/15 19:31
10	BRS	L10	236	laser and (((ic or (integrat\$3 near circuit) or semiconductor)))) and ((ink with marking))	USPAT	2003/09/15 19:47
11	BRS	L11	105	(((ic or (integrat\$3 near circuit) or semiconductor))) and (laser with (ink with marking))	USPAT	2003/09/15 19:32
12	BRS	L12	1	11 and (plasma with cleaning)	USPAT	2003/09/15 19:32
13	BRS	L13	26	("5369274" "5440123" "5583377" "5583378" "5620928" "5696666" "5747803" "5768774" "5943212" "5977543" "5986340" "5998241" "5999415" "6020637" "6034427" "6066512" "6103550" "6114760" "6184580" "6175497" "6242279" "6258631" "6323065" "6373131" "6395582" "6403401").PN.	USPAT	2003/09/15 19:45
14	BRS	L14	0	13 and (laser with ink with marking)	USPAT	2003/09/15 19:45
15	IS&R	L15	787	(219/121.43,121.36,121.4).CCLS.	USPAT	2003/09/15 19:46
16	IS&R	L16	2877	(134/1.1,1.2,2,30).CCLS.	USPAT	2003/09/15 19:46

	Type	L #	Hits	Search Text	DBs	Time Stamp
17	IS&R	L17	2319	(438/112,694,723,789,680).CCLS.	USPAT	2003/09/15 19:46
18	BRS	L18	5925	15 or 16 or 17	USPAT	2003/09/15 19:46
19	BRS	L19	6	18 and laser and (((ic or (integrat\$3 near circuit) or semiconductor))) and ((ink with marking))	USPAT	2003/09/15 19:57
20	BRS	L20	1355	18 and (plasma with chamber)	USPAT	2003/09/15 19:57
21	BRS	L21	241	20 and ((semiconductor or IC or (integrat\$3 with circuit)) with cleaning)	USPAT	2003/09/15 20:05
22	BRS	L22	108	21 and (argon with gas)	USPAT	2003/09/15 19:59
23	BRS	L23	18	22 and ionization	USPAT	2003/09/15 20:00
24	BRS	L24	7	22 and (ionization with voltage)	USPAT	2003/09/15 20:00
25	BRS	L25	0	21 and (remov\$3 with layer with packag\$3)	USPAT	2003/09/15 20:07
26	BRS	L26	97	21 and (remov\$3 with layer)	USPAT	2003/09/15 20:07
27	BRS	L27	48	21 and (remov\$3 with layer with cleaning)	USPAT	2003/09/15 20:07

	Type	L #	Hits	Search Text	DBs	Time Stamp
18	BRS	L18	52	17 and ((pure near noble near gas) or (argon with gas))	USPAT	2003/09/15 14:30
19	BRS	L19	50	18 and second\$1	USPAT	2003/09/15 15:22
20	BRS	L21	28	19 and watt\$1	USPAT	2003/09/15 15:23
21	BRS	L22	7	20 and millitorr\$1	USPAT	2003/09/15 16:29
22	IS&R	L23	1	("6418941").PN.	USPAT	2003/09/15 16:29
23	BRS	L24	0	23 and (continuous near voltage)	USPAT	2003/09/15 16:36
24	BRS	L26	0	25 and (continuous near voltage)	USPAT	2003/09/15 16:36
25	BRS	L27	0	25 and (continuous with voltage)	USPAT	2003/09/15 16:36
26	BRS	L28	0	23 and (continuous with voltage)	USPAT	2003/09/15 16:36
27	IS&R	L25	2	(("5451263") or ("5882423")).PN.	USPAT	2003/09/15 16:36
28	BRS	L29	6	("4529474" "4797178" "4816113" "4975146" "5174856"	USPAT	2003/09/15 16:41
29	BRS	L30	441	semiconductor with cleaning with plasma	USPAT	2003/09/15 16:42
30	BRS	L31	153	30 and (argon with gas)	USPAT	2003/09/15 16:43
31	BRS	L32	9	31 and second\$1 and watt\$1 and millitorr\$1	USPAT	2003/09/15 16:44
32	BRS	L33	6	32 not 22	USPAT	2003/09/15 16:44